# **HEF4521B**

# 24-stage frequency divider and oscillator Rev. 6 — 21 November 2011

Product data sheet

#### 1. **General description**

The HEF4521B consists of a chain of 24 toggle flip-flops with an overriding asynchronous master reset input (MR), and an input circuit that allows three modes of operation. The single inverting stage (A2 to Y2) functions as: a crystal oscillator, an input buffer for an external oscillator or in combination with A1 as an RC oscillator. The crystal oscillator operates in Low-power mode when pins  $V_{SS1}$  and  $V_{DD1}$  are supplied via external resistors.

Each flip-flop divides the frequency of the previous flip-flop by two, consequently the HEF4521B counts up to  $2^{24}$  = 16777216. The counting advances on the HIGH-to-LOW transition of the clock (A2). The outputs from each of the last seven stages (218 to 224) are available for additional flexibility.

It operates over a recommended V<sub>DD</sub> power supply range of 3 V to 15 V referenced to V<sub>SS</sub> (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input.

#### **Features and benefits** 2.

- Low power crystal oscillator operation
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

#### 3. Ordering information

### **Ordering information**

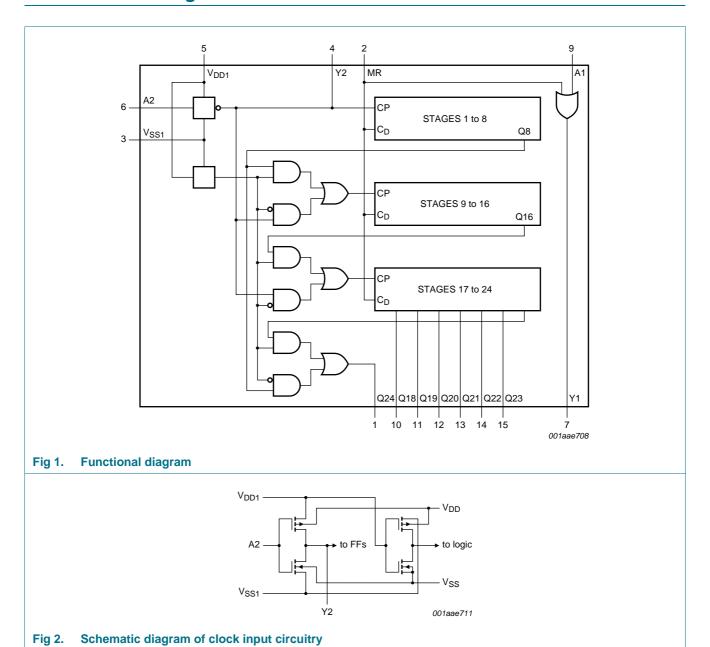
All types operate from -40 °C to +85 °C.

Type number	Package							
	Name	Description	Version					
HEF4521BP	DIP16	plastic dual in-line package; 16-leads (300 mil)	SOT38-4					
HEF4521BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					

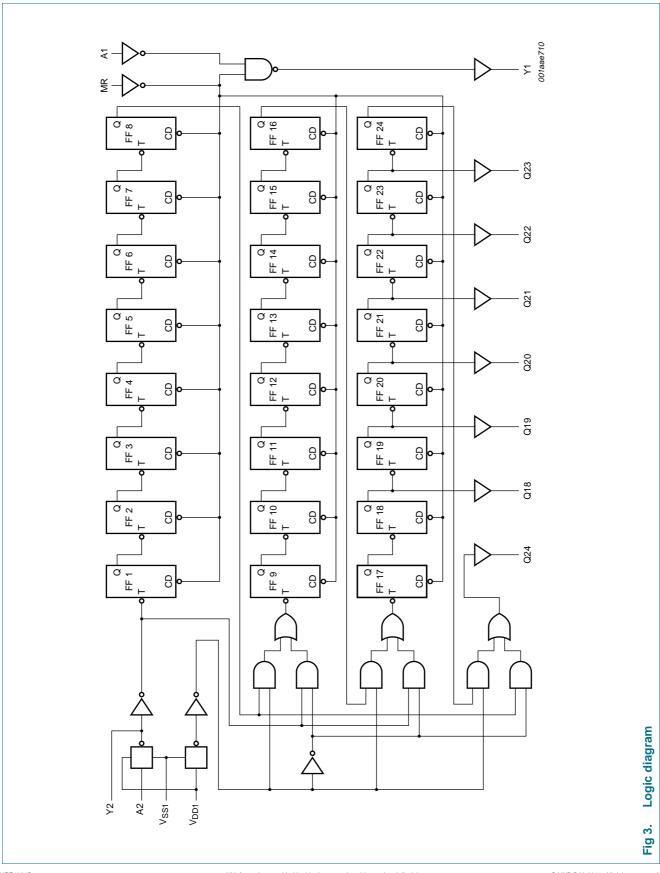


# 24-stage frequency divider and oscillator

# 4. Functional diagram



# 24-stage frequency divider and oscillator



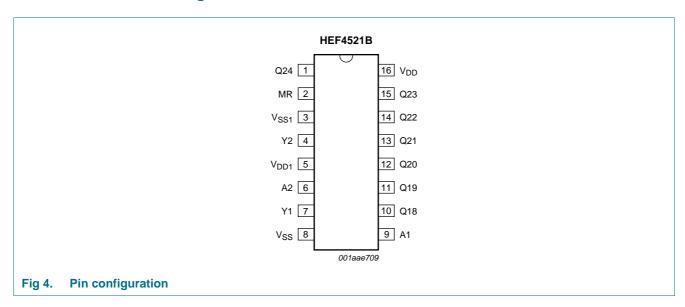
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# 24-stage frequency divider and oscillator

# 5. Pinning information

# 5.1 Pinning



# 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
MR	2	master reset input
V <sub>SS1</sub>	3	ground supply voltage 1
$V_{DD1}$	5	supply voltage 1
Y1, Y2	7, 4	external oscillator connection
V <sub>SS</sub>	8	ground supply voltage
A1, A2	9, 6	external oscillator connection
Q18 to Q24	10, 11, 12, 13, 14, 15, 1	output
$V_{DD}$	16	supply voltage

# 6. Count capacity

Table 3. Count capacity

Output	Count capacity
Q18	$2^{18} = 262144$
Q19	$2^{19} = 524288$
Q20	$2^{20} = 1048576$
Q21	$2^{21} = 2097152$
Q22	2 <sup>22</sup> = 4194304
Q23	$2^{23} = 8388608$
Q24	2 <sup>24</sup> = 16777216

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# 24-stage frequency divider and oscillator

# 7. Functional test

A test function has been included to reduce the test time required to test all 24 counter stages. This test function divides the counter into three 8-stage sections by connecting  $V_{SS1}$  to  $V_{DD}$  and  $V_{DD1}$  to  $V_{SS}$ . 255 counts are loaded into each of the 8-stage sections in parallel via A2 (connected to Y2). All flip-flops are now at a HIGH level. The counter is now returned to the normal 24-stage in series configuration by connecting  $V_{SS1}$  to  $V_{SS}$  and  $V_{DD1}$  to  $V_{DD}$ . Entering one more pulse into input A2 causes the counter to ripple from an all HIGH state to an all LOW state.

Table 4. Functional test sequence[1]

Inputs	1	Control to	erminal	S	Outputs	Remarks				
MR	MR A2 Y2 V <sub>SS1</sub>		$V_{DD1}$	Q18 to Q24						
Н	L	L	$V_{DD}$	$V_{SS}$	L	counter is in three 8-stage sections in parallel mode; A2 and Y2 are interconnected (Y2 is now input); counter is reset by MR.				
L	[2]	[2]	$V_{DD}$	$V_{SS}$	Н					
L	L	L	$V_{SS}$	$V_{SS}$	Н	V <sub>SS1</sub> is connected to V <sub>SS</sub> .				
L	Н	L	$V_{SS}$	$V_{SS}$	Н	the input A2 is made HIGH.				
L	Н	L	$V_{SS}$	$V_{DD}$	Н	$V_{DD1}$ is connected to $V_{DD}$ ; Y2 is now made floating and becomes an output; the device is now in the $2^{24}$ mode.				
L	$\downarrow$		$V_{SS}$	$V_{DD}$	L	counter ripples from an all HIGH state to an all LOW state.				

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level;  $\downarrow = HIGH$  to LOW transition.

# 8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
I <sub>OK</sub>	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I <sub>I/O</sub>	input/output current		-	±10	mA
I <sub>DD</sub>	supply current	to any supply terminal	-	±100	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+85	°C
P <sub>tot</sub>	total power dissipation	DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

<sup>[1]</sup> For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

<sup>[2] 255</sup> pulses are clocked into A2, Y2. The counter advances on the LOW to HIGH transition.

<sup>[2]</sup> For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

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# 9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
VI	input voltage		0	-	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V <sub>DD</sub> = 5 V	-	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	-	0.08	μs/V

# 10. Static characteristics

Table 7. Static characteristics

 $V_{SS} = 0$  V;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions		T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> = 85 °C		Unit
				Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_{O}  < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	$ I_O  < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level output voltage	$ I_{O}  < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub>	LOW-level output voltage	$ I_{O}  < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I <sub>OH</sub>	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_{O} = 4.6 \text{ V}$	5 V	-	-0.52	-	-0.44	-	-0.36	mΑ
		$V_0 = 9.5 \ V$	10 V	-	-1.3	-	-1.1	-	-0.9	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-	-3.6	-	-3.0	-	-2.4	mΑ
I <sub>OL</sub>	LOW-level output current	$V_0 = 0.4 \ V$	5 V	0.52	-	0.44	-	0.36	-	mΑ
		$V_0 = 0.5 \ V$	10 V	1.3	-	1.1	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	3.6	-	3.0	-	2.4	-	mΑ
I <sub>I</sub>	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I <sub>DD</sub>	supply current	I <sub>O</sub> = 0 A	5 V	-	20	-	20	-	150	μΑ
			10 V	-	40	-	40	-	300	μΑ
			15 V	-	80	-	80	-	600	μΑ
Cı	input capacitance		-	-	-	-	7.5	-	-	pF

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# 24-stage frequency divider and oscillator

# 11. Dynamic characteristics

Table 8. Dynamic characteristics

 $V_{SS} = 0 \text{ V; } T_{amb} = 25 \text{ °C; for test circuits see } \underline{Figure 6}$ ; unless otherwise specified.

t <sub>PHL</sub>	HIGH to LOW							
		A2 to Q18;	5 V	11 923 ns + (0.55 ns/pF)C <sub>L</sub>	-	950	1900	ns
	propagation delay	see <u>Figure 5</u>	10 V	339 ns + (0.23 ns/pF)C <sub>L</sub>	-	350	700	ns
			15 V	212 ns + (0.16 ns/pF)C <sub>L</sub>	-	220	440	ns
		Qn to Qn + 1;	5 V	13 ns + (0.55 ns/pF)C <sub>L</sub>	-	40	80	ns
		see Figure 5	10 V	4 ns + (0.23 ns/pF)C <sub>L</sub>	-	15	30	ns
			15 V	2 ns + (0.16 ns/pF)C <sub>L</sub>	-	10	20	ns
		MR to Qn	5 V	93 ns + (0.55 ns/pF)C <sub>L</sub>	-	120	240	ns
			10 V	44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
		A1 to Y1; see Figure 5	5 V	63 ns + (0.55 ns/pF)C <sub>L</sub>	-	90	180	ns
			10 V	24 ns + (0.23 ns/pF)C <sub>L</sub>	-	35	70	ns
			15 V	17 ns + (0.16 ns/pF)C <sub>L</sub>	-	25	50	ns
t <sub>PLH</sub>	LOW to HIGH	A2 to Q18;	5 V	11 923 ns + (0.55 ns/pF)C <sub>L</sub>	-	950	1900	ns
	propagation delay	see Figure 5	10 V	339 ns + (0.23 ns/pF)C <sub>L</sub>	-	350	700	ns
			15 V	212 ns + (0.16 ns/pF)C <sub>L</sub>	-	220	440	ns
		Qn to Qn + 1;	5 V	13 ns + (0.55 ns/pF)C <sub>L</sub>	-	40	80	ns
		see Figure 5	10 V	4 ns + (0.23 ns/pF)C <sub>L</sub>	-	15	30	ns
			15 V	2 ns + (0.16 ns/pF)C <sub>L</sub>	-	10	20	ns
		A1 to Y1;	5 V	33 ns + (0.55 ns/pF)C <sub>L</sub>	-	60	120	ns
		see Figure 5	10 V	19 ns + (0.23 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	12 ns + (0.16 ns/pF)C <sub>L</sub>	-	20	40	ns
t <sub>t</sub>	transition time	Qn; see Figure 5	5 V	10 ns + (1.00 ns/pF)C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C <sub>L</sub>	-	20	40	ns
t <sub>W</sub>	pulse width	A2 HIGH;	5 V		80	40	-	ns
		minimum width;	10 V		40	20	-	ns
		see <u>Figure 5</u>	15 V		30	15	-	ns
		MR HIGH;	5 V		70	35	-	ns
		minimum width;	10 V		40	20	-	ns
		see Figure 5	15 V		30	15	-	ns
t <sub>rec</sub>	recovery time	MR; see Figure 5	5 V		+20	-10	-	ns
			10 V		+15	-5	-	ns
			15 V		15	0	-	ns
f <sub>max</sub>	maximum frequency	A1; see Figure 5	5 V		6	12	-	MHz
			10 V		12	25	-	MHz
			15 V		17	35	-	MHz

<sup>[1]</sup> The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

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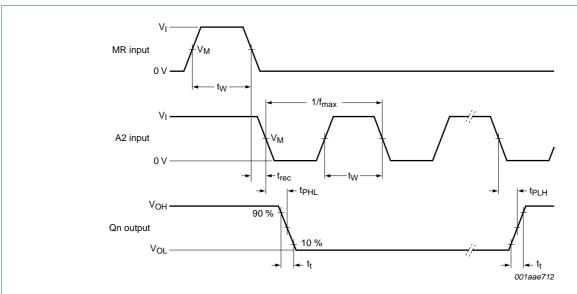
# 24-stage frequency divider and oscillator

Table 9. Dynamic power dissipation P<sub>D</sub>

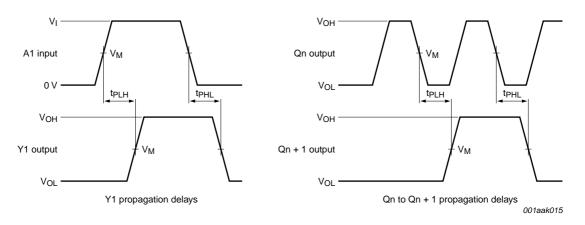
 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0 \text{ V}$ ;  $t_r = t_f \le 20 \text{ ns}$ ;  $T_{amb} = 25 \text{ °C}$ .

Symbol	Parameter	$V_{DD}$	Typical formula for P <sub>D</sub> (μW)	where:
$P_D$	dynamic power	5 V	$P_D = 1200 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz,
	dissipation	10 V	$P_D = 5100 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$f_0$ = output frequency in MHz,
		15 V	$P_D = 13050 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF,
				V <sub>DD</sub> = supply voltage in V,
				$\Sigma(C_L \times f_o)$ = sum of the outputs.

# 12. Waveforms



a. Pulse widths, maximum frequency, recovery and transition times and A2 to Qn propagation delays



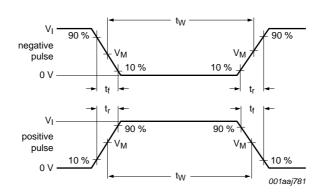
b. A1 to Y1, MR to Qn and Qn to Qn + 1 propagation delays

Measurement points are given in Table 10.

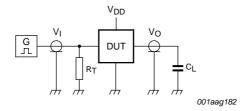
The logic levels  $V_{OH}$  and  $V_{OL}$  are typical output voltage levels that occur with the output load.

Fig 5. Waveforms showing measurement of dynamic characteristics

# 24-stage frequency divider and oscillator



### a. Input waveforms



### b. Test circuit

Test data is given in Table 10.

Definitions for test circuit:

Device Under Test (DUT);

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

Fig 6. Test circuit for switching times

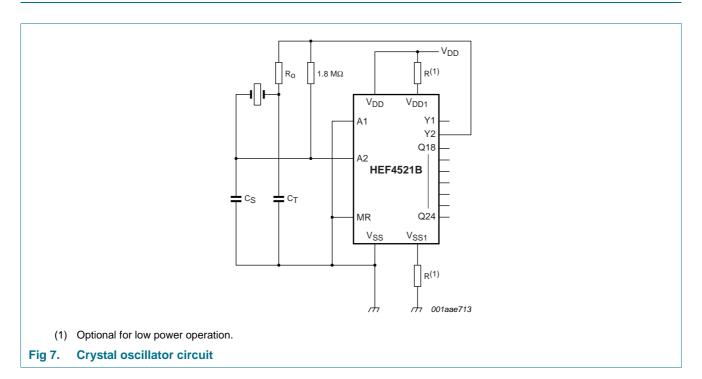
Table 10. Measurement points and test data

Supply voltage	Input	Input L							
	V <sub>I</sub>	V <sub>M</sub>	t <sub>r</sub> , t <sub>f</sub>	CL					
5 V to 15 V	$V_{DD}$	0.5V <sub>I</sub>	≤ 20 ns	50 pF					

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# 24-stage frequency divider and oscillator

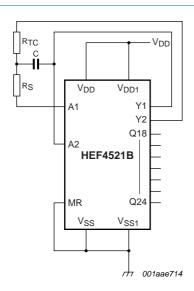
# 13. Application information



**Table 11. Typical characteristics for crystal oscillator** See *Figure 7*.

Parameter		500 kHz circ	cuit 50 kHz circu	it Unit	
Crystal characteristics	5				
Resonanc	e frequency	500	50	kHz	
Crystal cu	t	S	N	-	
Equivalen	t resistance; R <sub>S</sub>	1	6.2	kΩ	
External resistor/capa	citor values				
R <sub>o</sub>		47	750	kΩ	
C <sub>T</sub>		82	82	pF	
Cs		20	20	pF	

# 24-stage frequency divider and oscillator



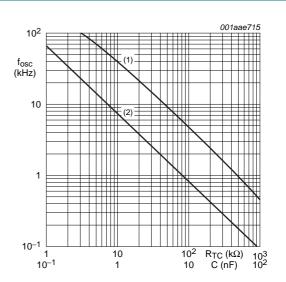
$$f\!\approx\!\frac{I}{2.3\times R_{TC}\times C}$$
 ;  $R_S\!\geq\!2R_{TC}$  , where:

f is in Hz, R is in  $\Omega,$  and C is in F.

$$R_S + R_{TC} < \frac{V_{IL(max)}}{I_{IJ}}$$
 , where:

 $V_{IL(max)}$  = maximum input voltage LOW; and  $I_{LI}$  = input leakage current.

Fig 8. RC oscillator circuit



 $V_{DD}$  = 10 V; The test circuit is shown in Figure 8.

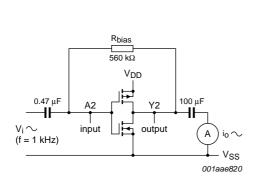
- (1)  $R_{TC}$ ; C = 1 nF;  $R_S \approx 2$   $R_{TC}$ .
- (2) C;  $R_{TC} = 56 \text{ k}\Omega$ ;  $R_S = 120 \text{ k}\Omega$ .

Fig 9. Oscillator frequency as a function of  $R_{\mbox{\scriptsize TC}}$  and  $\mbox{\scriptsize C}$ 

**Product data sheet** 

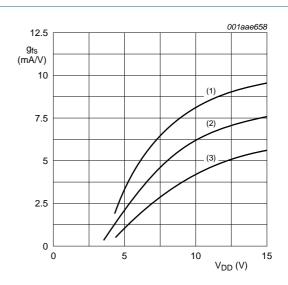
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# 24-stage frequency divider and oscillator



 $g_{fs} = d_{io}/d_{vi}$  with  $v_o$  constant (see Figure 11).

Fig 10. Test setup for measuring forward transconductance



- (1) Average + 2s.
- (2) Average.
- (3) Average 2s.

  Where 's' is the observed standard deviation.

Fig 11. Typical forward transconductance  $g_{fs}$  as a function of the supply voltage at  $T_{amb}$  = 25 °C

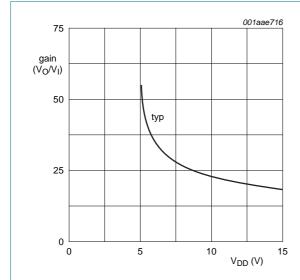


Fig 12. Voltage gain  $V_0/V_1$  as a function of supply voltage

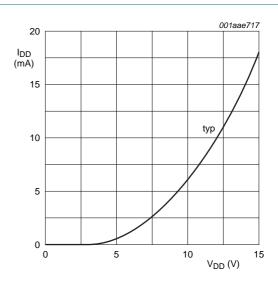


Fig 13. Supply current as a function of supply voltage

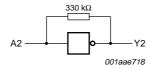


Fig 14. Test setup for measuring the Figure 12 and Figure 13 graphs

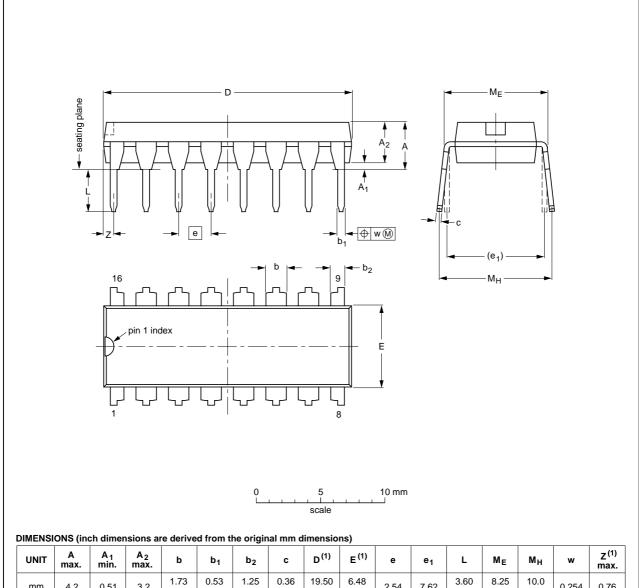
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# 14. Package outline

# DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



				,												
UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	С	D <sup>(1)</sup>	E <sup>(1)</sup>	е	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.02	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.1	0.3	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.03

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

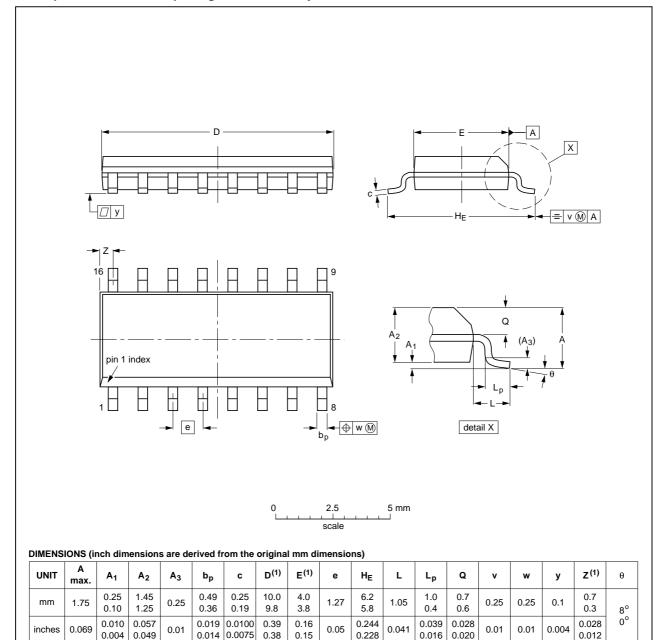
OUTLINE VERSION	REFERENCES				EUROPEAN	ISSUE DATE
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT38-4						<del>95-01-14</del> 03-02-13

Fig 15. Package outline SOT38-4 (DIP16)

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### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

Fig 16. Package outline SOT109-1 (SO16)

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# 24-stage frequency divider and oscillator

# 15. Revision history

# Table 12. Revision history

	•						
Document ID	Release date	Data sheet status	Change notice	Supersedes			
HEF4521B v.6	20111121	Product data sheet	-	HEF4521B v.5			
Modifications:	Section Applications removed						
	• Table 4: added references to Table note [1] and Table note [2]						
	<ul> <li><u>Table 7</u>: I<sub>OH</sub> minimum values changed to maximum</li> </ul>						
	• <u>Figure 11, F</u>	Figure note [1] and Figure no	ote [3]: space between '	2' and 's' removed			
HEF4521B v.5	20091105	Product data sheet	-	HEF4521B v.4			
HEF4521B v.4	20090421	Product data sheet	-	HEF4521B_CNV v.3			
HEF4521B_CNV v.3	19950101	Product specification	-	HEF4521B_CNV v.2			
HEF4521B_CNV v.2	19950101	Product specification	-	-			

**Product data sheet** 

# 24-stage frequency divider and oscillator

# 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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# 24-stage frequency divider and oscillator

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